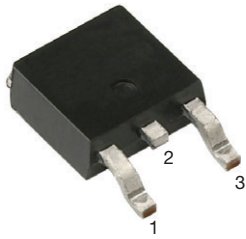
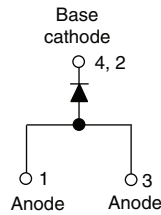


## High Performance Schottky Rectifier, 5.5 A



DPAK (TO-252AA)



### FEATURES

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability
- Popular DPAK outline
- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


**RoHS**  
 COMPLIANT  
 HALOGEN  
**FREE**

### DESCRIPTION

The VS-50WQ03FN-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	5.5 A
$V_R$	30 V
$V_F$ at $I_F$	See Electrical table
$I_{RM}$	58 mA at 125 °C
$T_J$ max.	150 °C
$E_{AS}$	10 mJ
Package	DPAK (TO-252AA)
Circuit configuration	Single

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform	5.5	A
$V_{RRM}$		30	V
$I_{FSM}$	$t_p = 5 \mu s$ sine	320	A
$V_F$	5 A <sub>pk</sub> , $T_J = 125$ °C	0.35	V
$T_J$	Range	-40 to +150	°C

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-50WQ03FN-M3	UNITS
Maximum DC reverse voltage	$V_R$	30	V
Maximum working peak reverse voltage	$V_{RWM}$		

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current See fig. 5	$I_{F(AV)}$	50 % duty cycle at $T_C = 136$ °C, rectangular waveform	5.5	A
Maximum peak one cycle non-repetitive surge current See fig. 7	$I_{FSM}$	5 $\mu s$ sine or 3 $\mu s$ rect. pulse	Following any rated load condition and with rated $V_{RRM}$ applied	320
		10 ms sine or 6 ms rect. pulse		130
Non-repetitive avalanche energy	$E_{AS}$	$T_J = 25$ °C, $I_{AS} = 2$ A, $L = 5$ mH	10	mJ
Repetitive avalanche current	$I_{AR}$	Current decaying linearly to zero in 1 $\mu s$ Frequency limited by $T_J$ maximum $V_A = 1.5 \times V_R$ typical	2.0	A



ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop See fig. 1	$V_{FM}^{(1)}$	5 A	$T_J = 25\text{ }^\circ\text{C}$	0.46	V
		10 A		0.53	
		5 A	$T_J = 125\text{ }^\circ\text{C}$	0.35	
		10 A		0.46	
Maximum reverse leakage current See fig. 2	$I_{RM}^{(1)}$	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_R$	3	mA
		$T_J = 125\text{ }^\circ\text{C}$		58	
Threshold voltage	$V_{F(TO)}$	$T_J = T_J \text{ maximum}$		0.19	V
Forward slope resistance	$r_t$			22.22	m $\Omega$
Typical junction capacitance	$C_T$	$V_R = 5\text{ }V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 $^\circ\text{C}$		590	pF
Typical series inductance	$L_S$	Measured lead to lead 5 mm from package body		5.0	nH

**Note**

(1) Pulse width < 300  $\mu\text{s}$ , duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum junction and storage temperature range	$T_J^{(1)}, T_{Stg}$			-40 to +150	$^\circ\text{C}$
Maximum thermal resistance, junction to case	$R_{thJC}$	DC operation See fig. 4		3.0	$^\circ\text{C/W}$
Approximate weight				0.3	g
				0.01	oz.
Marking device		Case style DPAK (TO-252AA)		50WQ03FN	

**Note**

(1)  $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink

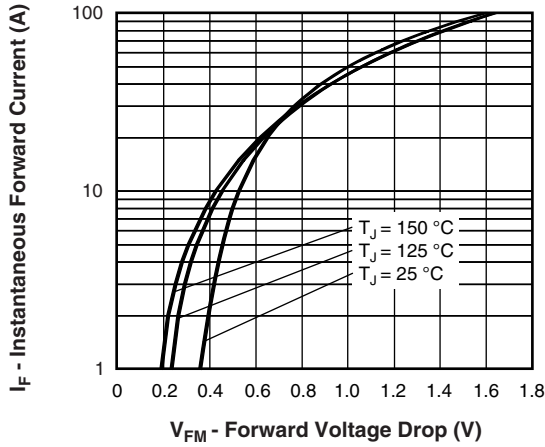


Fig. 1 - Maximum Forward Voltage Drop Characteristics

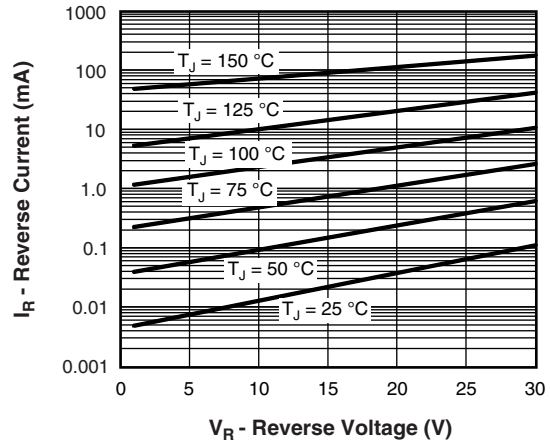


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

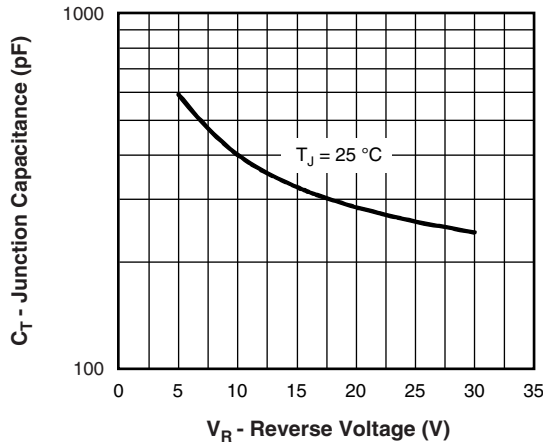


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

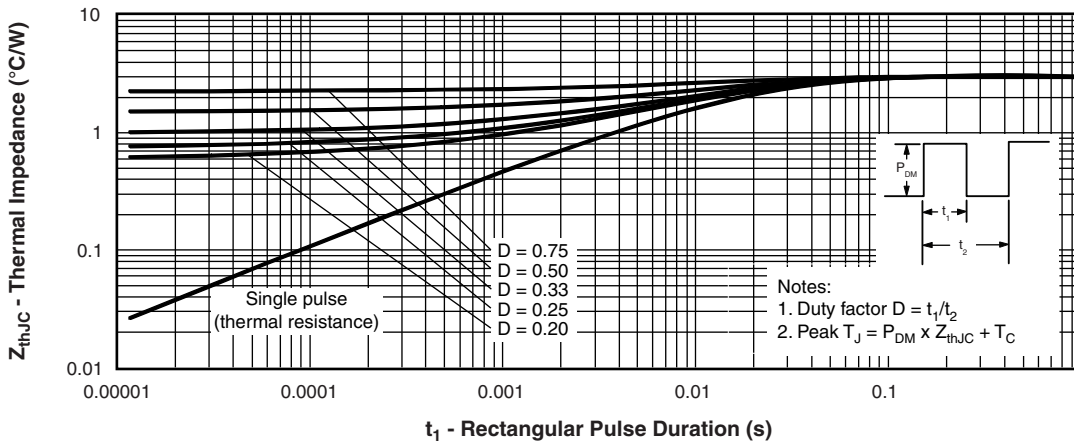


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

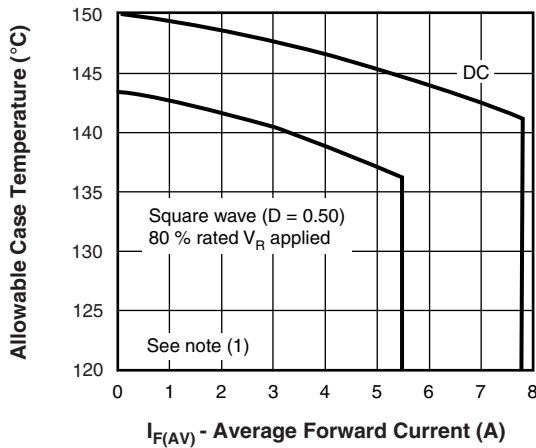


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

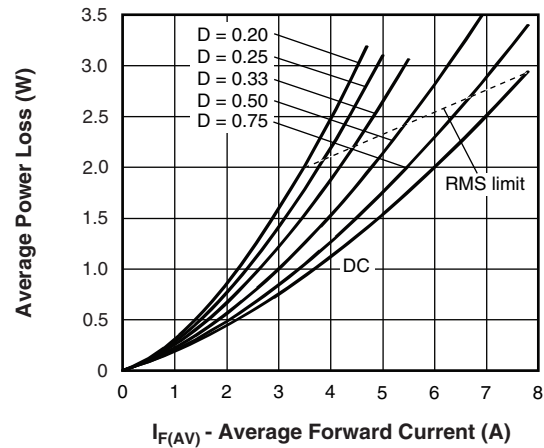


Fig. 6 - Forward Power Loss Characteristics

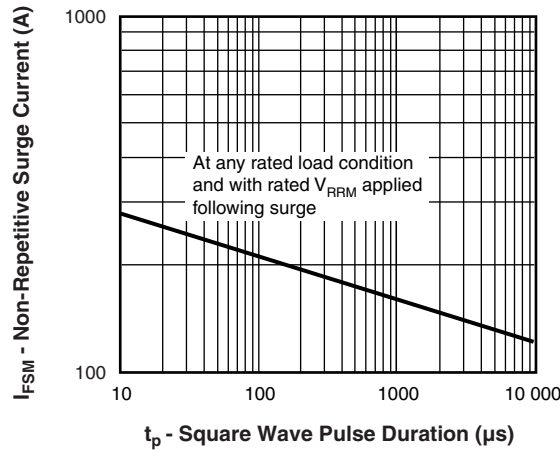


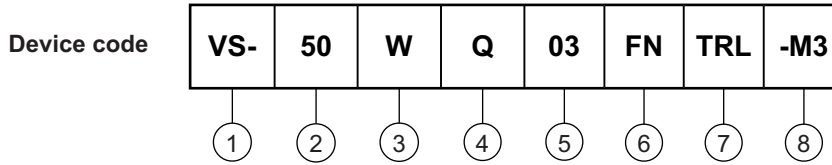
Fig. 7 - Maximum Non-Repetitive Surge Current

**Note**

- (1) Formula used:  $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$ ;
- $P_d$  = forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);
- $P_{d_{REV}}$  = inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1} = 80\%$  rated  $V_R$



ORDERING INFORMATION TABLE



- 1** - Vishay Semiconductors product
- 2** - Current rating (5.5 A)
- 3** - Package identifier:  
W = DPAK
- 4** - Schottky "Q" series
- 5** - Voltage rating (03 = 30 V)
- 6** - FN = TO-252AA (DPAK)
- 7** -
  - None = tube
  - TR = tape and reel
  - TRL = tape and reel (left oriented)
  - TRR = tape and reel (right oriented)
- 8** - Environmental digit:  
-M3 = halogen-free, RoHS-compliant and terminations lead (Pb)-free

<b>ORDERING INFORMATION</b> (Example)			
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-50WQ03FN-M3	75	3000	Antistatic plastic tube
VS-50WQ03FNTR-M3	2000	2000	13" diameter reel
VS-50WQ03FNTRL-M3	3000	3000	13" diameter reel
VS-50WQ03FNTRR-M3	3000	3000	13" diameter reel

<b>LINKS TO RELATED DOCUMENTS</b>	
Dimensions	<a href="http://www.vishay.com/doc?95627">www.vishay.com/doc?95627</a>
Part marking information	<a href="http://www.vishay.com/doc?95176">www.vishay.com/doc?95176</a>
Packaging information	<a href="http://www.vishay.com/doc?95033">www.vishay.com/doc?95033</a>